3.3 V 200 MHz 1:4 LVCMOS/LVTTL Low Skew Fanout Buffer

Description

The NB3M8304C is 1:4 fanout buffer with LVCMOS/LVTTL input and output. The device supports the core supply voltage of 3.3 V (V_{DD} pin) and output supply voltage of 2.5 V or 3.3 V (V_{DDO} pin). The V_{DDO} pin powers the four single ended LVCMOS/LVTTL outputs.

The NB3M8304C is Form, Fit and Function (pin to pin) compatible to ICS8304 and ICS8304I. The NB3M8304C is qualified for industrial operating temperature range.

Features

- Input Clock Frequency up to 200 MHz
- Low Output to Output Skew: 45 ps max
- Low Part to Part Skew: 500 ps max
- Low Additive RMS Phase Jitter
- Input Clock Accepts LVCMOS/ LVTTL Levels
- Operating Voltage:
 - Core Supply: $V_{DD} = 3.3 \text{ V} \pm 5\%$
 - Output Supply: $V_{DDO} = 3.3 \text{ V} \pm 5\% \text{ or } 2.5 \text{ V} \pm 5\%$
- Operating Temperature Range:
- Industrial: -40° C to $+85^{\circ}$ C
- These Devices are Pb-Free and are RoHS Compliant

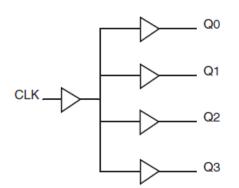
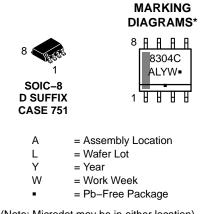


Figure 1. Block Diagram



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(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

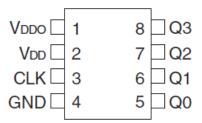


Figure 2. Pin Configuration (Top View)

Table 1. PIN DESCRIPTION

| Pin Number | Name | Туре | Description |
|------------|--------|----------------------|------------------------------------|
| 1 | VDDO | Output Power | Clock output Supply pin. |
| 2 | VDD | Input and Core Power | Input and Core Supply pin. |
| 3 | CLK | LVCMOS/LVTTL Input | Clock Input. Internally pull-down. |
| 4 | GND | Ground | Supply Ground. |
| 5, 6, 7, 8 | Q[0:3] | LVCMOS/LVTTL Output | LVCMOS/LVTTL Clock output. |

Table 2. MAXIMUM RATINGS

| Symbol | Parameter | Condition | Min | Max | Unit |
|-------------------|--|--|---------|-----------------------|------|
| $V_{DD,} V_{DDO}$ | Power Supply | | - | 4.6 | V |
| VI | Input Voltage | | -0.5 | V _{DD} + 0.5 | V |
| T _{stg} | Storage Temperature | | -65 | +150 | °C |
| θ_{JA} | Thermal Resistance (Junction-to-Ambient) SOIC-8 | 0 lfpm 500 lfpm | | 80 55 | °C/W |
| θJC | Thermal Resistance (Junction to Case) (Note 1) | | | 12–17 | °C/W |
| T _{sol} | Wave Solder | 3 sec | | 265 | °C |
| MSL | Moisture Sensitivity SOIC-8 | Indefinite Time Out of Drypack (Note 2) | Level 1 | | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. JEDEC standard multilayer board – 2S2P (2 signal, 2 power)

2. For additional information, see Application Note AND8003/D.

Table 3. DC OPERATING CHARACTERISTICS (V_DD = 3.3 V $\pm 5\%$; T_A = -40°C to +85°C)

| Symbol | Parameter | Condition | Min | Тур | Max | Unit |
|------------------|--|--|-------|-----|-------|------|
| R _{IN} | Input Pull-down Resistor (CLK Pin) | | | 51 | | kΩ |
| C _{IN} | Input Capacitance | | | 4 | | pF |
| R _{OUT} | Output Impedance (Note 3) | | 5 | 7 | 12 | Ω |
| C _{PD} | Power Dissipation Capacitance (per output) | V _{DD} = V _{DDO} = 3.465 V | | 15 | | pF |
| V_{DD} | Core Supply Voltage | | 3.135 | 3.3 | 3.465 | V |
| I _{IH} | Input High Current | V _{IN} = V _{DD} = 3.465 V | | | 150 | μΑ |
| IIL | Input Low Current | V_{DD} 3.465 V, V_{IN} = 0.0 V | -0.5 | | | μΑ |

3. Outputs terminated with 50 Ω to V_DDO/2. See Figure 4 for supply considerations.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Table 4. DC OPERATING CHARACTERISTICS (T_A = $-40^\circ C$ to $+85^\circ C)$

| Symbol | Parameter | Condition | Min | Max | Unit |
|-------------------------|-------------------------------------|------------------------------------|-------|-------|------|
| V _{DD} = 3.3 V | ′ ±5%, V _{DDO} = 2.5 V ±5% | | • | | |
| V _{DDO} | Output Supply Voltage | | 2.375 | 2.625 | V |
| V _{OH} | Output HIGH Voltage | I _{OH} = -100 μA | 2.2 | | V |
| | | I _{OH} = -16 mA | 2.1 | | |
| | | 50 Ω to V_DDO/2 | 2.1 | | |
| V _{OL} | Output LOW Voltage | I _{OL} = 16 mA | | 0.25 | |
| | | I _{OL} = 100 μA | | 0.2 | V |
| | | 50 Ω to V _{DDO} /2 | | 0.5 | |

V_{DD} = V_{DDO} = 3.3 V ±5%

| V _{DDO} | Output Supply Voltage | | 3.135 | 3.465 | V |
|------------------|-----------------------|---------------------------|-------|-------|---|
| V _{OH} | Output HIGH Voltage | I _{OH} = –16 mA | 2.9 | | V |
| | | I _{OH} = −100 μA | 3 | | |
| | | 50 Ω to V_{DDO}/2 | 2.6 | | |
| V _{OL} | Output LOW Voltage | l _{OL} = 16 mA | | 0.25 | |
| | | I _{OL} = 100 μA | | 0.15 | V |
| | | 50 Ω to V_{DDO}/2 | | 0.5 | |

Table 5. DC OPERATING CHARACTERISTICS

 $({\sf T}_{\sf A}=-40^{\circ}{\rm C} \text{ to }+85^{\circ}{\rm C}; \, {\sf V}_{\sf DD}={\sf V}_{\sf DDO}=3.3 \; {\sf V} \; \pm5\%; \, {\sf V}_{\sf DD}=3.3 \; {\sf V} \; \pm5\%, \, {\sf V}_{\sf DDO}=2.5 \; {\sf V} \; \pm5\%)$

| Symbol | Parameter | Condition | Min | Max | Unit |
|------------------|--------------------------------|-----------|------|-----------------------|------|
| I _{DD} | Quiescent Power Supply Current | No Load | | 15 | mA |
| I _{DDO} | Quiescent Power Supply Current | No Load | | 8 | mA |
| V _{IH} | Input HIGH Voltage | | 2 | V _{DD} + 0.3 | V |
| V _{IL} | Input LOW Voltage | | -0.3 | 1.3 | V |

Table 6. AC CHARACTERISTICS (Note 4)

| Symbol | Parameter | Condition | Min | Тур | Max | Unit |
|------------------------|---|--|-----|-----|-----|------|
| T _A = -40°C | to +85°C; V_{DD} = 3.3 V ±5%, V_{DDO} = 3.3 V ±5% | | | | | |
| F _{IN} | Input Frequency | | | | 200 | MHz |
| t _{PLH} | Propagation Delay (Note 5) | Fin = 200 MHz | 1.9 | | 3.3 | ns |
| t _{SKEW} | Output to Output Skew(Note 6) | | | 25 | 45 | ps |
| | Part to Part Skew (Note 6) | | | 250 | 800 | ps |
| t _{SKEWDC} | Output Duty Cycle (see Figure 3) | Fin = 200 MHz | 40 | | 60 | % |
| tr/tf | Output rise and fall times (Note 7) | 30% to 70%, RS = 33 Ω , CL = 10 pF | 250 | | 500 | ps |

T_A = -40°C to +85°C; V_{DD} = 3.3 V ±5%, V_{DDO} = 2.5 V ±5%

| F _{IN} | Input Frequency | | | | 200 | MHz |
|---------------------|-------------------------------------|--------------------------------------|-----|-----|-----|-----|
| t _{PLH} | Propagation Delay (Note 5) | Fin = 200 MHz | 2.2 | | 3.7 | ns |
| t _{SKEW} | Output to Output Skew(Note 6) | | | 25 | 45 | ps |
| | Part to Part Skew (Note 6) | | | 250 | 500 | ps |
| t _{SKEWDC} | Output Duty Cycle (see Figure 3) | Fin = 200 MHz | 40 | | 60 | % |
| tr/tf | Output rise and fall times (Note 7) | 30% to 70%, RS = 33 Ω, CL = 10 pF | 200 | | 500 | ps |

4. Clock input with 50% duty cycle. Outputs terminated with 50 Ω to V_{DDO}/2. See Figures 3 and 4.

5. Measured from $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output. 6. Similar input conditions and the same supply voltages. Measured at $V_{DDO}/2$. See Figures 3 and 4. 7. RS is Series Resistance and CL is Load Capacitance at the clock outputs.

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

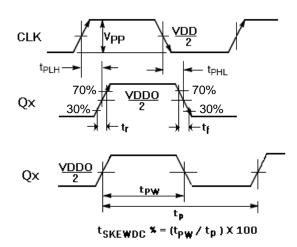
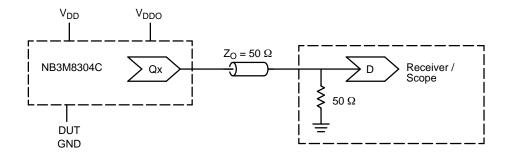


Figure 3. AC Reference Measurement



| Spec Condition: | TEST SETUP V _{DD} : | TEST SETUP V _{DDO} : | TEST SETUP DUT GND: |
|--|------------------------------|-------------------------------|---------------------|
| $V_{DD}=V_{DDO}=3.3~V~\pm5\%$ | 1.65 V ±5% | 1.65 V ±5% | -1.65 V ±5% |
| V_{DD} = 3.3 V ±5%; V_{DDO} = 2.5 V ±5% | 2.05 V ±5% | 1.25 V ±5% | -1.25 V ±5% |

Figure 4. Output Driver Typical Device Evaluation and Termination Setup

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|---------------|---------------------|-----------------------|
| NB3M8304CDG | SOIC-8 (Pb-Free) | 98 Units / Rail |
| NB3M8304CDR2G | SOIC-8 (Pb-Free) | 2500 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR 3. 4. EMITTER EMITTER 5. BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: CATHODE 1 PIN 1. 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT 6. IOUT IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: PIN 1. GROUND BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE P-SOURCE 3 P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE 2. ANODE SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC COMMON CATHODE/VCC 3 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 COMMON ANODE/GND 8. STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. 4. DRAIN, #2 GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 DRAIN 1 7. 8. **MIRROR 1** STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. LINE 1 OUT 8. STYLE 27: PIN 1. ILIMIT 2 OVI 0 UVLO З. 4. INPUT+ 5. SOURCE SOURCE 6. SOURCE 7. 8 DRAIN

DATE 16 FEB 2011

STYLE 4: ANODE ANODE PIN 1. 2. ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE #2 3. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. 4. GATE 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE 2. EMITTER 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW_TO_GND 2. DASIC OFF DASIC_SW_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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